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PATENT NUMBER

U.S. UTILITY Patent Application

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O.I.P.E.	PATENT DATE	
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APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER	1
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Kurt Petersen Nadim Maluf Wendell McCulley John Logan

Single crystal silicon sensor with high aspect ratio and curvilinear structures and associated method

(Attached in pocket on right inside flap)

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1	ORIGINAL				CROSS R	EFERENCE	E(S)	1.2		
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TERMINAL	DRAWINGS			CLAIMS ALLOWED		
DISCLAIMER	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.	
The term of this patent subsequent to (date)				NOTICE OF ALLOWANCE MAILED		
subsequent to (date) has been disclaimed.	(Assistant Examiner)		(Date)			
The term of this patent shall					X	
of U.S Patent. No.				ISSUE FEE		
				Amount Due	Date	
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this patent have been disclaimed.	(Legal Instrume	ents Examiner)	(Date)			
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